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May 2016

# 2N5401 Amplifier Transistor

#### **Features**

- Collector-Emitter Voltage: V<sub>CEO</sub> = 150V
   Collector Dissipation: P<sub>C</sub> (max) = 625mW
- Suffix "-C" means Conter Collector (1. Emitter 2. Collector 3. Base)



#### **Ordering Information**

Part Number	Top Mark	Package	Packing Method	Pack Quantity	
2N5401YBU	2N5401	TO-92 3L	Bulk	10000	
2N5401YTA	2N5401	TO-92 3L	Ammo	2000	

#### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-160	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-150	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-600	mA
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to 150	°C

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#### Thermal Characteristics(1)

Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Max.	Unit
В	Total Device Dissipation	625	mW
P <sub>D</sub>	Derate above 25°C	5	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

#### Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

#### **Electrical Characteristics**

Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Symbol Parameter		Conditions		Min.	Тур.	Max.	Unit
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage		$I_C = -100 \mu A, I_E = 0$		-160			V
BV <sub>CEO</sub>	V <sub>CEO</sub> Collector-Emitter Breakdown Voltage <sup>()</sup>		$I_C = -1 \text{ mA}, I_B = 0$		-150			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage		$I_E = -10 \mu A, I_C = 0$		-5			V
I <sub>CBO</sub>	Collector Cut-Off Current		$V_{CB} = -120 \text{ V}, I_{E} = 0$				-50	μΑ
I <sub>EBO</sub>	Emitter Cut-Off Current		$V_{EB} = -3 \text{ V, } I_{C} = 0$				-50	μΑ
	DC Current Gain <sup>(2)</sup>		I <sub>C</sub> = -1 mA, V <sub>CE</sub> = -5 V		30			
h			$I_{\rm C} = -10  {\rm mA},$	Standard Class	60		240	
h <sub>FE1</sub>			$V_{CE} = -5 V$	Y Class	120		240	
			$I_C = -50 \text{ mA}, V_{CE} = -5 \text{ V}$		50			
V	Collector-Emitter Saturation Voltage <sup>(2)</sup>		$I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$				-0.2	V
V <sub>CE(sat)</sub>			$I_C = -50 \text{ mA}, I_B = -5 \text{ mA}$				-0.5	V
V	Base-Emitter Saturation Voltage <sup>(2)</sup>		$I_{\rm C} = -10  {\rm mA},  I_{\rm B} =$	= -1 mA			-1.0	V
V <sub>BE(sat)</sub>			$I_C = -50 \text{ mA}, I_B = -5 \text{ mA}$				-1.0	V
f <sub>T</sub>	Current Gain Bandwidth Product		I <sub>C</sub> = -10 mA, V <sub>CE</sub> = -10 V, f = 100 MHz		100		400	MHz
C <sub>ob</sub>	Output Capacitance		V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz				6	pF
N <sub>F</sub>	Noise Figure $I_{C} = -250 \mu\text{A}, V_{CE} = -5 \text{ V,R}$ $f = 10 \text{ Hz to } 15.7 \text{ kHz}$					8	dB	

#### Note:

2. Pulse Test: Pulse Width≤300µs, Duty Cycle≤2%.

### **Typical Characteristics**

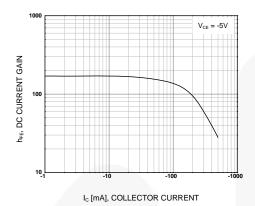


Figure 1. DC current Gain

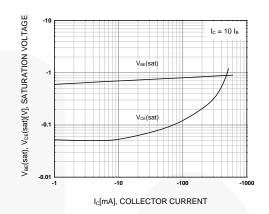


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

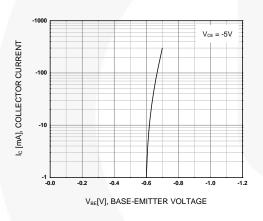


Figure 3. Base-Emitter On Voltage

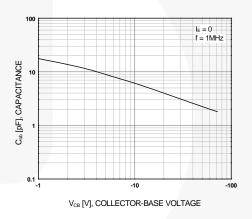


Figure 4. Output Capacitance

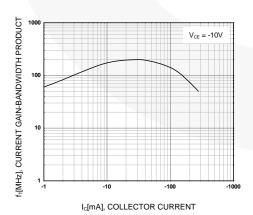


Figure 5. Current Gain Bandwidth Product







#### NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC.
  ALL DIMENSIONS ARE IN MILLIMETERS.
  DRAWING CONFORMS TO ASME Y14.5M-2009.
  DRAWING FILENAME: MKT-ZAO3FREV3.
  FAIRCHILD SEMICONDUCTOR.
- B. C. D. E.





NOTES: UNLESS OTHERWISE SPECIFIED

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